Supporting Information

Fabrication and Simulation of V-Shape Ag Nanorods as High-Performance SERS Substrates

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![Graph showing Raman Enhancement Factor vs. Resonance Wavelength]
**Figure SI.** Raman EF comparisons of a straight AgNR’s 2nd (black), 3rd (red), 4th (blue) and 5th (pink) modes. The 2nd mode has the strongest Raman enhancement factors at resonance wavelengths above 500 nm.